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<u>Vishay Semiconductor/Diodes Division</u> <u>VFT3060C-M3/4W</u>

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Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of VFT3060C-M3/4W - DIODE SCHOTTKY 30A 60V ITO-220AB

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VFT3060C

COMPLIANT

FREE

Vishay General Semiconductor

Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.38 \text{ V}$ at $I_F = 5 \text{ A}$



| ITO-220AB | | | | | |
|---------------|--|--|--|--|--|
| 123 | | | | | |
| VFT3060C | | | | | |
| PIN 1 O PIN 2 | | | | | |
| PIN 3 O | | | | | |

| PRIMARY CHARACTERISTICS | | | | |
|---|---------------------|--|--|--|
| I _{F(AV)} | 2 x 15 A | | | |
| V_{RRM} | 60 V | | | |
| I _{FSM} | 170 A | | | |
| V _F at I _F = 15 A | 0.57 V | | | |
| T _J max. | 150 °C | | | |
| Package | ITO-220AB | | | |
| Diode variation | Dual Common Cathode | | | |

FEATURES

- · Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Solder bath temperature 275 °C max. 10 s, per JESD 22-B106
- · Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

MECHANICAL DATA

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted) | | | | | |
|--|------------|-----------------------------------|-------------|------|--|
| PARAMETER | | SYMBOL | VFT3060C | UNIT | |
| Maximum repetitive peak reverse voltage | | V_{RRM} | 60 | V | |
| Maximum average forward rectified current (fig. 1) | per device | I _{F(AV)} | 30 | | |
| | per diode | | 15 | A | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | | I _{FSM} | 170 | А | |
| Voltage rate of change (rated V _R) | | dV/dt | 10 000 | V/µs | |
| Isolation voltage from termal to heatsink t = 1 min | | V_{AC} | 1500 | V | |
| Operating junction and storage temperature range | | T _J , T _{STG} | -55 to +150 | °C | |

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Datasheet of VFT3060C-M3/4W - DIODE SCHOTTKY 30A 60V ITO-220AB





VFT3060C

Vishay General Semiconductor

| ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | | | |
|---|------------------------|--|---------------------------------|------|------|------|--|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT | |
| Instantaneous forward voltage per diode | I _F = 5.0 A | T _A = 25 °C | - V _F ⁽¹⁾ | 0.47 | - | . V | |
| | I _F = 7.5 A | | | 0.51 | - | | |
| | I _F = 15 A | | | 0.60 | 0.70 | | |
| | I _F = 5.0 A | T _A = 125 °C | | 0.38 | - | | |
| | I _F = 7.5 A | | | 0.44 | - | | |
| | I _F = 15 A | | | 0.57 | 0.65 | | |
| Reverse current per diode | V _R = 60 V | $T_A = 25 ^{\circ}\text{C}$ $T_A = 125 ^{\circ}\text{C}$ | I _R ⁽²⁾ | - | 1.2 | - mA | |
| | v _R = 00 v | | | 20 | 45 | | |

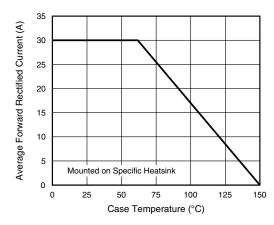
Notes

- (1) Pulse test: 300 µs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

| THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted) | | | | | |
|---|------------|----------------|----------|--------|--|
| PARAMETER | | SYMBOL | VFT3060C | UNIT | |
| Typical thermal resistance | per diode | $R_{	heta JC}$ | 6.0 | °C/W | |
| | per device | | 4.8 | - C/VV | |

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|----------------|-----------------|--------------|---------------|---------------|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | |
| ITO-220AB | VFT3060C-M3/4W | 1.76 | 4W | 50/tube | Tube | |

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)





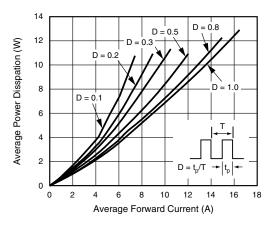


Fig. 2 - Forward Power Dissipation Characteristics



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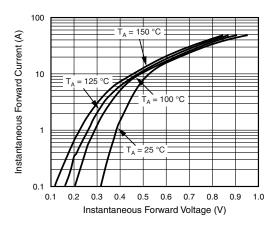


Fig. 3 - Typical Instantaneous Forward Characteristics

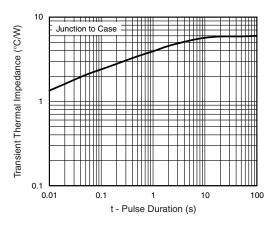


Fig. 5 - Typical Transient Thermal Impedance

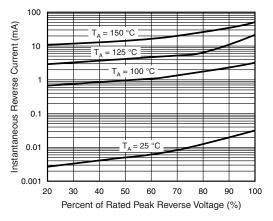


Fig. 4 - Typical Reverse Characteristics

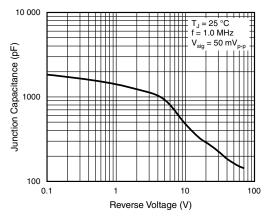
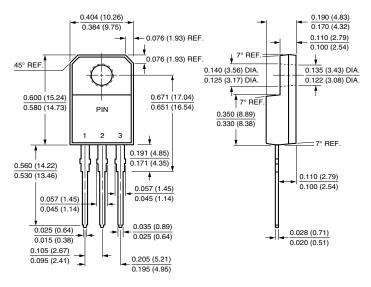


Fig. 6 - Typical Junction Capacitance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

ITO-220AB



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